1-Ω SPDT ANALOG SWITCH
5-V/3.3-V SINGLE-CHANNEL 2:1 MULTIPLEXER/DEMULTIPLEXER

Check for Samples: TS5A3159A

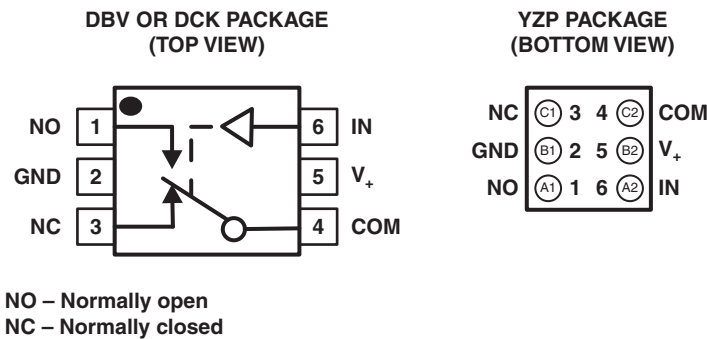## FEATURES

- **Isolation in Power-Down Mode, $V_+ = 0$**
- **Pin Compatible With TS5A3159**
- **Specified Break-Before-Make Switching**
- **Low On-State Resistance (1 Ω)**
- **Control Inputs Are 5.5-V Tolerant**
- **Low Charge Injection**
- **Excellent On-State Resistance Matching**
- **Low Total Harmonic Distortion (THD)**
- **1.65-V to 5.5-V Single-Supply Operation**
- **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**
- **ESD Performance Tested Per JESD**
  - **2000-V Human-Body Model (A114-B, Class II)**
  - **1000-V Charged-Device Model (C101)**

APPLICATIONS

- **Cell Phones**
- **PDAs**
- **Portable Instrumentation**
- **Audio and Video Signal Routing**
- **Low-Voltage Data Acquisition Systems**
- **Communication Circuits**
- **Modems**
- **Hard Drives**
- **Computer Peripherals**
- **Wireless Terminals and Peripherals**

DESCRIPTION

The TS5A3159A is a single-pole double-throw (SPDT) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers low on-state resistance and excellent on-state resistance matching with the break-before-make feature, to prevent signal distortion during the transferring of a signal from one channel to another. The device has an excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.

DBV OR DCK PACKAGE
(TOP VIEW)

NO	1	6	IN
GND	2	5	V_+
NC	3	4	COM

YZP PACKAGE
(BOTTOM VIEW)

NC	(C1) 3	4 (C2)	COM
GND	(B1) 2	5 (B2)	V_+
NO	(A1) 1	6 (A2)	IN

NO – Normally open
NC – Normally closed

FUNCTION TABLE

IN	NC TO COM, COM TO NC	NO TO COM, COM TO NO
L	ON	OFF
H	OFF	ON

⚠ Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TS5A3159A

SUMMARY OF CHARACTERISTICS[1]

Configuration	2:1 Multiplexer/ Demultiplexer (1 × SPDT)
Number of channels	1
On-state resistance (r_{on})	1.1 Ω
On-state resistance match (Δr_{on})	0.1 Ω
On-state resistance flatness ($r_{on(flat)}$)	0.15 Ω
Turn-on/turn-off time (t_{ON}/t_{OFF})	20 ns/15 ns
Break-before-make time (t_{BBM})	12 ns
Charge injection (Q_C)	–20 pC
Bandwidth (BW)	100 MHz
OFF isolation (O_{ISO})	–65 dB at 1 MHz
Crosstalk (X_{TALK})	–66 dB at 1 MHz
Total harmonic distortion (THD)	0.01%
Leakage current ($I_{NO(OFF)}/I_{NC(OFF)}$)	±20 nA
Power-supply current (I_+)	50 nA
Package options	6-pin DBV, DCK, or YZP

(1) $V_+ = 5$ V, $T_A = 25°C$

ORDERING INFORMATION[1]

T_A	PACKAGE[2]		ORDERABLE PART NUMBER	TOP-SIDE MARKING[3]
–40°C to 85°C	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	TS5A3159AYZPR	_ _ _JJ_
	SOT (SOT-23) – DBV	Reel of 3000	TS5A3159ADBVR	JAJ_
	SOT (SC-70) – DCK[3]	Reel of 3000	TS5A3159ADCKR	JJ_

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
(3) DBV/DCK: The actual top-side marking has one additional character that designates the wafer fab/assembly site.
YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

Product Folder Link(s): *TS5A3159A*

Absolute Minimum and Maximum Ratings[1] [2]

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_+	Supply voltage range[3]		−0.5	6.5	V
V_{NO}, V_{NC} V_{COM}	Analog voltage range[3] [4] [5]		−0.5	$V_+ + 0.5$	V
I_K	Analog port diode current	$V_{N\,C}$, V_{NO}, V_{COM} < 0	−50		mA
$I_{N\,O}$, $I_{N\,C}$,	On-state switch current	V_{NO}, $V_{N\,C}$, V_{COM} = 0 to V_+	−200	200	mA
I_{COM}	On-state peak switch current[6]	V_{NO}, $V_{N\,C}$, V_{COM} = 0 to V_+	−400	400	mA
V_I	Digital input voltage range[3] [4]		−0.5	6.5	V
I_{IK}	Digital input clamp current	V_I < 0	−50		mA
I_+	Continuous current through V_+			100	mA
I_{GND}	Continuous current through GND		−100	100	mA
θ_{JA}	Package thermal impedance[7]	DBV package		165	°C/W
		DCK package		259	
		YZP package		123	
T_A	Absolute maximum operating temperature[8]	DBV or DCK package		150	°C
		YZP package		125	
T_{stg}	Storage temperature range		−65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
(3) All voltages are with respect to ground, unless otherwise specified.
(4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
(5) This value is limited to 5.5 V maximum.
(6) Pulse at 1-ms duration <10% duty cycle
(7) The package thermal impedance is calculated in accordance with JESD 51-7.
(8) The lifetime of the device will be reduced if the device operates continually at this temperature.

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Electrical Characteristics for 5-V Supply[1]

V_+ = 4.5 V to 5.5 V, T_A = −40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}, V_{NC}					0		V_+	V
Peak on resistance	r_{peak}	$0 \le$ (V_{NO} or V_{NC}) $\le V_+$, I_{COM} = −100 mA,	Switch on, See Figure 15	25°C	4.5 V		0.8	1.1	Ω
				Full				1.5	
On-state resistance	r_{on}	V_{NO} or V_{NC} = 2.5 V, I_{COM} = −100 mA,	Switch on, See Figure 15	25°C	4.5 V		0.7	0.9	Ω
				Full				1.1	
On-state resistance match between channels	Δr_{on}	V_{NO} or V_{NC} = 2.5 V, I_{COM} = −100 mA,	Switch on, See Figure 15	25°C	4.5 V		0.05	0.1	Ω
				Full				0.1	
On-state resistance flatness	$r_{on(flat)}$	$0 \le$ (V_{NO} or V_{NC}) $\le V_+$, I_{COM} = −100 mA,	Switch on, See Figure 15	25°C	4.5 V		0.15		Ω
		V_{NO} or V_{NC} = 1 V, 1.5 V, 2.5 V, I_{COM} = −100 mA,	Switch on, See Figure 15	25°C			0.1	0.25	
				Full				0.25	
NC, NO off leakage current	$I_{NC(OFF)}$, $I_{NO(OFF)}$	V_{NC} or V_{NO} = 1 V, V_{COM} = 1 V to 4.5 V, or V_{NC} or V_{NO} = 4.5 V, V_{COM} = 1 V to 4.5 V,	Switch off, See Figure 16	25°C	5.5 V	−20	2	20	nA
				Full		−100		100	
	$I_{NC(PWROFF)}$, $I_{NO(PWROFF)}$	V_{NC} or V_{NO} = 0 to 5.5 V, V_{COM} = 5.5 V to 0,	Switch off, See Figure 16	25°C	0 V	−1	0.2	1	μA
				Full		−20		20	
NC, NO on leakage current	$I_{NC(ON)}$, $I_{NO(ON)}$	V_{NC} or V_{NO} = 1 V, V_{COM} = Open, or V_{NC} or V_{NO} = 4.5 V, V_{COM} = Open,	Switch on, See Figure 17	25°C	5.5 V	−20	2	20	nA
				Full		−100		100	
COM off leakage current	$I_{COM(PWROFF)}$	V_{NC} or V_{NO} = 0 to 5.5 V, V_{COM} = 5.5 V to 0,	Switch off, See Figure 16	25°	0 V	−1	0.1	1	μA
				Full		−20		20	
COM on leakage current	$I_{COM(ON)}$	V_{NC} or V_{NO} = Open, V_{COM} = 1 V, or V_{NC} or V_{NO} = Open, V_{COM} = 4.5 V,	Switch on, See Figure 17	25°C	5.5 V	−20	2	20	nA
				Full		−100		100	
Digital Input (IN)									
Input logic high	V_{IH}			Full		2.4		5.5	V
Input logic low	V_{IL}			Full		0		0.8	
Input leakage current	I_{IH}, I_{IL}	V_I = 5.5 V or 0		25°C	5.5 V	−2		2	nA
				Full		100		100	

(1)   The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

Product Folder Link(s): TS5A3159A

Electrical Characteristics for 5-V Supply[1] (Continued)

V_+ = 4.5 V to 5.5 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	$V_{COM} = V_+$, R_L = 50 Ω,	C_L = 35 pF, See Figure 19	25°C	5 V	1	12	30	ns
				Full	4.5 V to 5.5 V	1		35	
Turn-off time	t_{OFF}	$V_{COM} = V_+$, R_L = 50 Ω,	C_L = 35 pF, See Figure 19	25°C	5 V	1	5	20	ns
				Full	4.5 V to 5.5 V	1		30	
Break-before-make time	t_{BBM}	$V_{NC} = V_{NO} = V_+$, R_L = 50 Ω,	C_L = 35 pF, See Figure 20	25°C	5 V		6		ns
				Full	4.5 V to 5.5 V	1		20	
Charge injection	Q_C	V_{GEN} = 0, R_{GEN} = 0,	C_L = 1 nF, See Figure 24	25°C	5 V		–20		pC
NC, NO off capacitance	$C_{NC\,(OFF)}$, $C_{NO(OFF)}$	V_{NC} or $V_{NO} = V_+$ or GND, Switch off,	See Figure 18	25°C	5 V		18		pF
NC, NO on capacitance	$C_{NC(ON)}$, $C_{NO(ON)}$	V_{NC} or $V_{NO} = V_+$ or GND, Switch on,	See Figure 18	25°C	5 V		55		pF
COM on capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch on,	See Figure 18	25°C	5 V		55		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND,	See Figure 18	25°C	5 V		2		pF
Bandwidth	BW	R_L = 50 Ω, Switch on,	See Figure 21	25°C	5 V		100		MHz
Off isolation	O_{ISO}	R_L = 50 Ω, f = 1 MHz,	Switch off, See Figure 22	25°C	5 V		–64		dB
Crosstalk	X_{TALK}	R_L = 50 Ω, f = 1 MHz,	Switch on, See Figure 23	25°C	5 V		–64		dB
Total harmonic distortion	THD	R_L = 600 Ω, C_L = 50 pF,	f = 200 Hz to 20 kHz, See Figure 25	25°C	5 V		0.004		%
Supply									
Positive supply current	I_+	$V_I = V_+$ or GND,	Switch on or off	25°C	5.5 V		10	50	nA
				Full				500	

(1)   The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

Product Folder Link(s): TS5A3159A

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Electrical Characteristics for 3.3-V Supply[1]

V_+ = 3 V to 3.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}, V_{NC}					0		V_+	V
Peak on resistance	r_{peak}	$0 \le (V_{NO}$ or $V_{NC}) \le V_+$, I_{COM} = –100 mA,	Switch on, See Figure 15	25°C	3 V		1.3	1.6	Ω
				Full				2	
On-state resistance	r_{on}	V_{NO} or V_{NC} = 2 V, I_{COM} = –100 mA,	Switch on, See Figure 15	25°C	3 V		1.2	1.5	Ω
				Full				1.7	
On-state resistance match between channels	Δr_{on}	V_{NO} or V_{NC} = 2 V, 0.8 V, I_{COM} = –100 mA,	Switch on, See Figure 15	25°C	3 V		0.1	0.15	Ω
				Full				0.15	
On-state resistance flatness	$r_{on(flat)}$	$0 \le (V_{NO}$ or $V_{NC}) \le V_+$, I_{COM} = –100 mA,	Switch on, See Figure 15	25°C	3 V		0.2		Ω
		V_{NO} or V_{NC} = 2 V, 0.8 V, I_{COM} = –100 mA,	Switch on, See Figure 15	25°C			0.15	0.3	
				Full				0.3	
NC, NO off leakage current	$I_{NC(OFF)}$, $I_{NO(OFF)}$	V_{NC} or V_{NO} = 1 V, V_{COM} = 1 V to 3 V, or V_{NC} or V_{NO} = 3 V, V_{COM} = 1 V to 3 V,	Switch off, See Figure 16	25°C	3.6 V	–20	2	20	nA
				Full		–50		50	
	$I_{NC(PWROFF)}$, $I_{NO(PWROFF)}$	V_{NC} or V_{NO} = 0 to 3.6 V, V_{COM} = 3.6 V to 0,	Switch off, See Figure 16	25°C	0 V	–1	0.2	1	μA
				Full		–15		15	
NC, NO on leakage current	$I_{NC(ON)}$, $I_{NO(ON)}$	V_{NC} or V_{NO} = 1 V, V_{COM} = Open, or V_{NC} or V_{NO} = 3 V, V_{COM} = Open,	Switch on, See Figure 17	25°C	3.6 V	–10	2	10	nA
				Full		–20		20	
COM off leakage current	$I_{COM(PWROFF)}$	V_{NC} or V_{NO} = 3.6 V to 0, V_{COM} = 0 to 3.6 V,	Switch off, See Figure 16	25°	0 V	–1	0.2	1	μA
				Full		–15		15	
COM on leakage current	$I_{COM(ON)}$	V_{NC} or V_{NO} = Open, V_{COM} = 1 V, or V_{NC} or V_{NO} = Open, V_{COM} = 3 V,	Switch on, See Figure 17	25°C	3.6 V	–10	2	10	nA
				Full		–20		20	
Digital Input (IN)									
Input logic high	V_{IH}			Full		2.4		5.5	V
Input logic low	V_{IL}			Full		0		0.8	
Input leakage current	I_{IH}, I_{IL}	V_I = 5.5 V or 0		25°C	3.6 V	–2		2	nA
				Full		–100		100	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

Product Folder Link(s): *TS5A3159A*

Electrical Characteristics for 3.3-V Supply[(1)] (Continued)

V_+ = 3 V to 3.6 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	$V_{COM} = V_+$, $R_L = 50\ \Omega$,	C_L = 35 pF, See Figure 19	25°C	3.3 V	5	16	35	ns
				Full	3 V to 3.6 V	3		50	
Turn-off time	t_{OFF}	$V_{COM} = V_+$, $R_L = 50\ \Omega$,	C_L = 35 pF, See Figure 19	25°C	3.3 V	1	9	20	ns
				Full	3 V to 3.6 V	1		30	
Break-before-make time	t_{BBM}	$V_{NC} = V_{NO} = V_+$, $R_L = 50\ \Omega$,	C_L = 35 pF, See Figure 20	25°C	3.3 V		9		ns
				Full	3 V to 3.6 V	1		40	
Charge injection	Q_C	$V_{GEN} = 0$, $R_{GEN} = 0$,	C_L = 1 nF, See Figure 24	25°C	3.3 V		–11		pC
NC, NO off capacitance	$C_{NC\ (OFF)}$, $C_{NO(OFF)}$	V_{NC} or $V_{NO} = V_+$ or GND, Switch off,	See Figure 18	25°C	3.3 V		18		pF
NC, NO on capacitance	$C_{NC(ON)}$, $C_{NO(ON)}$	V_{NC} or $V_{NO} = V_+$ or GND, Switch on,	See Figure 18	25°C	3.3 V		55		pF
COM on capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch on,	See Figure 18	25°C	3.3 V		55		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND,	See Figure 18	25°C	3.3 V		2		pF
Bandwidth	BW	$R_L = 50\ \Omega$, Switch on,	See Figure 21	25°C	3.3 V		100		MHz
Off isolation	O_{ISO}	$R_L = 50\ \Omega$, f = 1 MHz,	Switch off, See Figure 22	25°C	3.3 V		–64		dB
Crosstalk	X_{TALK}	$R_L = 50\ \Omega$, f = 1 MHz,	Switch on, See Figure 23	25°C	3.3 V		–64		dB
Total harmonic distortion	THD	$R_L = 600\ \Omega$, C_L = 50 pF,	f = 20 Hz to 20 kHz, See Figure 25	25°C	3.3 V		0.01		%
Supply									
Positive supply current	I_+	$V_I = V_+$ or GND,	Switch on or off	25°C	3.6 V		10	25	nA
				Full				100	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

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TEXAS INSTRUMENTS

Electrical Characteristics for 2.5-V Supply[(1)]

$V_+ = 2.3$ V to 2.7, $T_A = -40°C$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}, V_{NC}					0		V_+	V
Peak on resistance	r_{peak}	$0 \le (V_{NO}$ or $V_{NC}) \le V_+$, $I_{COM} = -8$ mA,	Switch on, See Figure 15	25°C	2.3 V		1.8	2.5	Ω
				Full				2.7	
On-state resistance	r_{on}	V_{NO} or $V_{NC} = 1.8$ V, $I_{COM} = -8$ mA,	Switch on, See Figure 15	25°C	2.3 V		1.5	2	Ω
				Full				2.4	
On-state resistance match between channels	Δr_{on}	V_{NO} or $V_{NC} = 1.8$ V, $I_{COM} = -8$ mA,	Switch on, See Figure 15	25°C	2.3 V		0.15	0.2	Ω
				Full				0.2	
On-state resistance flatness	$r_{on(flat)}$	$0 \le (V_{NO}$ or $V_{NC}) \le V_+$, $I_{COM} = -8$ mA,	Switch on, See Figure 15	25°C	2.3 V		0.6		Ω
		V_{NO} or $V_{NC} = 0.8$ V, 1.8 V, $I_{COM} = -8$ mA,	Switch on, See Figure 15	25°C			0.6	1	
				Full				1	
NC, NO off leakage current	$I_{NC(OFF)}$, $I_{NO(OFF)}$	V_{NC} or $V_{NO} = 0.5$ V, $V_{COM} = 0.5$ V to 2.3 V, or V_{NC} or $V_{NO} = 2.3$ V, $V_{COM} = 0.5$ V to 2.3 V,	Switch off, See Figure 16	25°C	2.7 V	−20	2	20	nA
				Full		−50		50	
	$I_{NC(PWROFF)}$, $I_{NO(PWROFF)}$	V_{NC} or $V_{NO} = 0$ to 3.6 V, $V_{COM} = 3.6$ V to 0,	Switch off, See Figure 16	25°C	0 V	−1	0.1	1	µA
				Full		−10		10	
NC, NO on leakage current	$I_{NC(ON)}$, $I_{NO(ON)}$	V_{NC} or $V_{NO} = 0.5$ V, $V_{COM} =$ Open, or V_{NC} or $V_{NO} = 2.2$ V, $V_{COM} =$ Open,	Switch on, See Figure 17	25°C	2.7 V	−10	2	10	nA
				Full		−20		20	
COM off leakage current	$I_{COM(PWROFF)}$	V_{NC} or $V_{NO} = 2.7$ V to 0, $V_{COM} = 0$ to 2.7 V,	Switch off, See Figure 16	25°	0 V	−1	0.1	10	µA
				Full		−10		20	
COM on leakage current	$I_{COM(ON)}$	V_{NC} or $V_{NO} =$ Open, $V_{COM} = 0.5$ V, or V_{NC} or $V_{NO} =$ Open, $V_{COM} = 2.2$ V,	Switch on, See Figure 17	25°C	2.7 V	−10	2	10	nA
				Full		−20		20	
Digital Input (IN)									
Input logic high	V_{IH}			Full		1.8		5.5	V
Input logic low	V_{IL}			Full		0		0.6	
Input leakage current	I_{IH}, I_{IL}	$V_I = 5.5$ V or 0		25°C	2.7 V	−2		2	nA
				Full		20		20	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

Product Folder Link(s): TS5A3159A

Electrical Characteristics for 2.5-V Supply[(1)] (Continued)

$V_+ = 2.3$ V to 2.7, $T_A = -40°C$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	$V_{COM} = V_+$, $R_L = 50\ \Omega$,	$C_L = 35$ pF, See Figure 19	25°C	2.5 V	5	22	40	ns
				Full	2.3 V to 2.7 V	5		50	
Turn-off time	t_{OFF}	$V_{COM} = V_+$, $R_L = 50\ \Omega$,	$C_L = 35$ pF, See Figure 19	25°C	2.5 V	2	6	35	ns
				Full	2.3 V to 2.7 V	2		50	
Break-before-make time	t_{BBM}	$V_{NC} = V_{NO} = V_+$, $R_L = 50\ \Omega$,	$C_L = 35$ pF, See Figure 20	25°C	2.5 V	2	13	35	ns
				Full	2.3 V to 2.7 V	2		45	
Charge injection	Q_C	$V_{GEN} = 0$, $R_{GEN} = 0$,	$C_L = 1$ nF, See Figure 24	25°C	2.5 V		–7		pC
NC, NO off capacitance	$C_{NC\ (OFF)}$, $C_{NO(OFF)}$	V_{NC} or $V_{NO} = V_+$ or GND, Switch off,	See Figure 18	25°C	2.5 V		18		pF
NC, NO on capacitance	$C_{NC(ON)}$, $C_{NO(ON)}$	V_{NC} or $V_{NO} = V_+$ or GND, Switch on,	See Figure 18	25°C	2.5 V		55		pF
COM on capacitance	$C_{COM(ON)}$	$V_{COM} = V_+$ or GND, Switch on,	See Figure 18	25°C	2.5 V		55		pF
Digital input capacitance	C_I	$V_I = V_+$ or GND,	See Figure 18	25°C	2.5 V		2		pF
Bandwidth	BW	$R_L = 50\ \Omega$, Switch on,	See Figure 21	25°C	2.5 V		100		MHz
Off isolation	O_{ISO}	$R_L = 50\ \Omega$, f = 1 MHz,	Switch off, See Figure 22	25°C	2.5 V		–64		dB
Crosstalk	X_{TALK}	$R_L = 50\ \Omega$, f = 1 MHz,	Switch on, See Figure 23	25°C	2.5 V		–64		dB
Total harmonic distortion	THD	$R_L = 600\ \Omega$, $C_L = 50$ pF,	f = 20 Hz to 20 kHz, See Figure 25	25°C	2.5 V		0.02		%
Supply									
Positive supply current	I_+	$V_I = V_+$ or GND,	Switch on or off	25°C	2.7 V		10	20	nA
				Full				50	

(1)   The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.
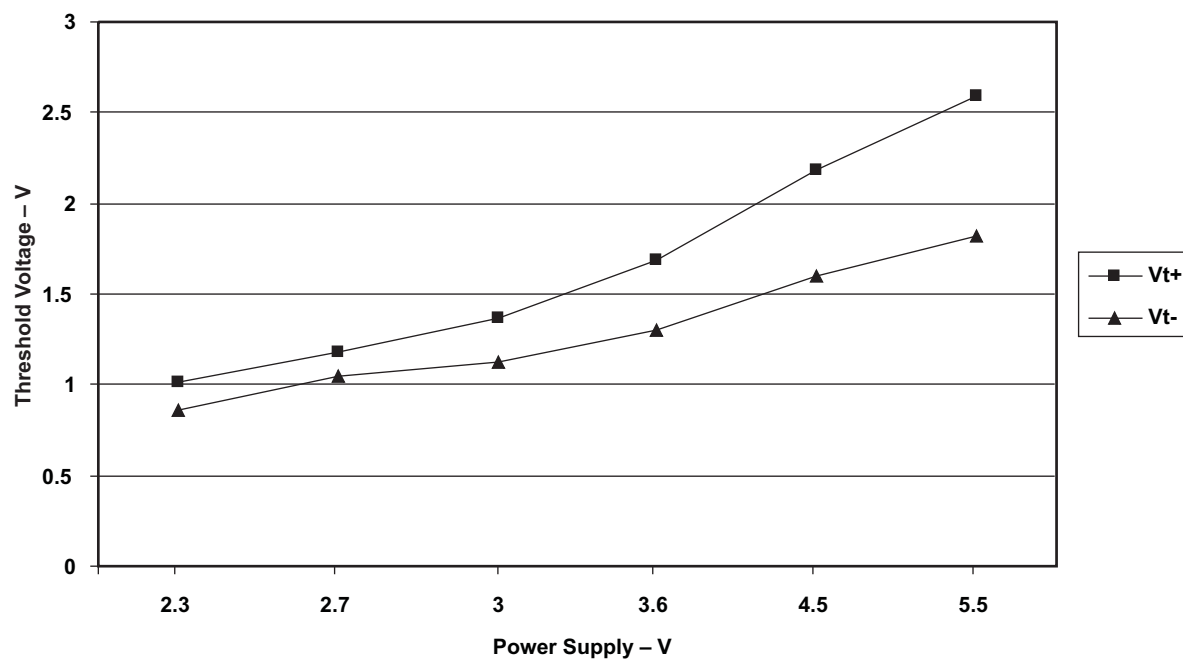
Figure 1. Logic Threshold vs Power Supply

Product Folder Link(s): *TS5A3159A*

Electrical Characteristics for 1.8-V Supply[1]

V_+ = 1.65 V to 1.95 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V_{COM}, V_{NO}, V_{NC}					0		V_+	V
Peak on resistance	r_{peak}	$0 \leq (V_{NO}$ or $V_{NC}) \leq V_+$, I_{COM} = –2 mA,	Switch on, See Figure 15	25°C	1.65 V		5		Ω
				Full				15	
On-state resistance	r_{on}	V_{NO} or V_{NC} = 1.5 V, I_{COM} = –2 mA,	Switch on, See Figure 15	25°C	1.65 V		2	2.5	Ω
				Full				3.5	
On-state resistance match between channels	Δr_{on}	V_{NO} or V_{NC} = 1.5 V, I_{COM} = –2 mA,	Switch on, See Figure 15	25°C	1.65 V		0.15	0.4	Ω
				Full				0.4	
On-state resistance flatness	$r_{on(flat)}$	$0 \leq (V_{NO}$ or $V_{NC}) \leq V_+$, I_{COM} = –8 mA,	Switch on, See Figure 15	25°C	1.65 V		5		Ω
		V_{NO} or V_{NC} = 0.6 V, 1.5 V, I_{COM} = –2 mA,	Switch on, See Figure 15	25°C			4.5		
				Full					
NC, NO off leakage current	$I_{NC(OFF)}$, $I_{NO(OFF)}$	V_{NC} or V_{NO} = 0.3 V, V_{COM} = 0.3 V to 1.65 V, or V_{NC} or V_{NO} = 1.65 V, V_{COM} = 0.3 V to 1.65 V,	Switch off, See Figure 16	25°C	1.95 V	–5	2	5	nA
				Full		–20		20	
	$I_{NC(PWROFF)}$ $I_{NO(PWROFF)}$	V_{NC} or V_{NO} = 0 to 1.95 V, V_{COM} = 1.95 V to 0,	Switch off, See Figure 16	25°C	0 V	–1	0.1	1	µA
				Full		–5		5	
NC, NO on leakage current	$I_{NC(ON)}$, $I_{NO(ON)}$	V_{NC} or V_{NO} = 0.3 V, V_{COM} = Open, or V_{NC} or V_{NO} = 1.65 V, V_{COM} = Open,	Switch on, See Figure 17	25°C	1.95 V	–5	2	5	nA
				Full		–20		20	
COM off leakage current	$I_{COM(PWROFF)}$	V_{NC} or V_{NO} = 1.95 V to 0, V_{COM} = 0 to 1.95 V,	Switch off, See Figure 16	25°	0 V	–1	0.1	7	µA
				Full		–5		5	
COM on leakage current	$I_{COM(ON)}$	V_{NC} or V_{NO} = Open, V_{COM} = 0.3 V, or V_{NC} or V_{NO} = Open, V_{COM} = 1.65 V,	Switch on, See Figure 17	25°C	1.95 V	–5	2	5	nA
				Full		–20		20	
Digital Input (IN)									
Input logic high	V_{IH}			Full		1.5		5.5	V
Input logic low	V_{IL}			Full		0		0.6	
Input leakage current	I_{IH}, I_{IL}	V_I = 5.5 V or 0		25°C	1.95 V	–2		2	nA
				Full		20		20	

(1)   The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

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Electrical Characteristics for 1.8-V Supply[1] (Continued)

V_+ = 1.65 V to 1.95 V, T_A = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		T_A	V_+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	t_{ON}	V_{COM} = V_+, R_L = 50 Ω,	C_L = 35 pF, See Figure 19	25°C	1.8 V	10	35	70	ns
				Full	1.65 V to 1.95 V	10		75	
Turn-off time	t_{OFF}	V_{COM} = V_+, R_L = 50 Ω,	C_L = 35 pF, See Figure 19	25°C	1.8 V	2	15	40	ns
				Full	1.65 V to 1.95 V	2		50	
Break-before-make time	t_{BBM}	V_{NC} = V_{NO} = V_+, R_L = 50 Ω,	C_L = 35 pF, See Figure 20	25°C	1.8 V		22		ns
				Full	1.65 V to 1.95 V	2		70	
Charge injection	Q_C	V_{GEN} = 0, R_{GEN} = 0,	C_L = 1 nF, See Figure 24	25°C	1.8 V		–4		pC
NC, NO off capacitance	$C_{NC\,(OFF)}$, $C_{NO(OFF)}$	V_{NC} or V_{NO} = V_+ or GND, Switch off,	See Figure 18	25°C	1.8 V		18		pF
NC, NO on capacitance	$C_{NC(ON)}$, $C_{NO(ON)}$	V_{NC} or V_{NO} = V_+ or GND, Switch on,	See Figure 18	25°C	1.8 V		55		pF
COM on capacitance	$C_{COM(ON)}$	V_{COM} = V_+ or GND, Switch on,	See Figure 18	25°C	1.8 V		55		pF
Digital input capacitance	C_I	V_I = V_+ or GND,	See Figure 18	25°C	1.8 V		2		pF
Bandwidth	BW	R_L = 50 Ω, Switch on,	See Figure 21	25°C	1.8 V		105		MHz
Off isolation	O_{ISO}	R_L = 50 Ω, f = 1 MHz,	Switch off, See Figure 22	25°C	1.8 V		64		dB
Crosstalk	X_{TALK}	R_L = 50 Ω, f = 1 MHz,	Switch on, See Figure 23	25°C	1.8 V		64		dB
Total harmonic distortion	THD	R_L = 600 Ω, C_L = 50 pF,	f = 20 Hz to 20 kHz, See Figure 25	25°C	1.8 V		0.06		%
Supply									
Positive supply current	I_+	V_I = V_+ or GND,	Switch on or off	25°C	1.95 V		5	15	µA
				Full				50	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

Product Folder Link(s): *TS5A3159A*

TYPICAL PERFORMANCE
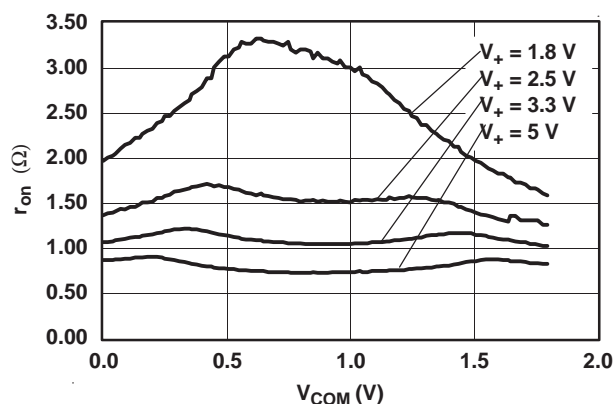
Figure 2. r$_{on}$ vs V$_{COM}$
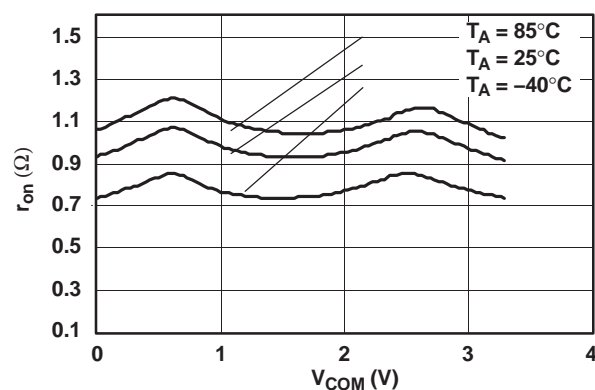
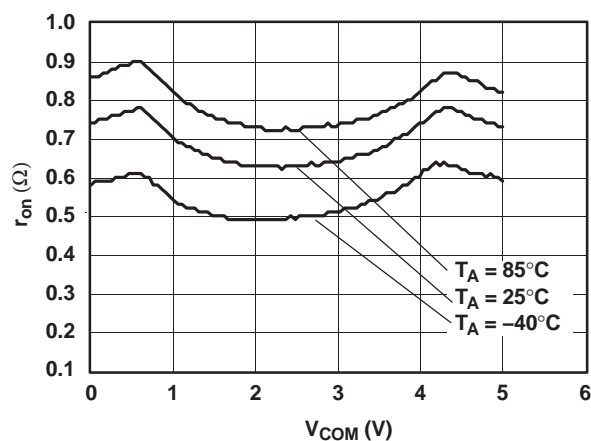Figure 3. r$_{on}$ vs V$_{COM}$ (V$_+$ = 3.3 V)

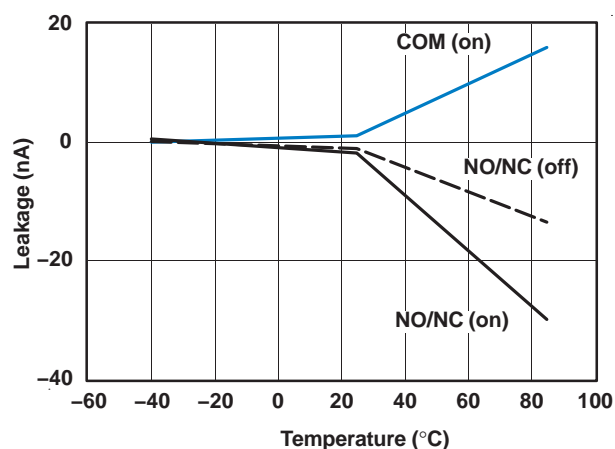Figure 4. r$_{on}$ vs V$_{COM}$ (V$_+$ = 5 V)

Figure 5. Leakage Current vs Temperature
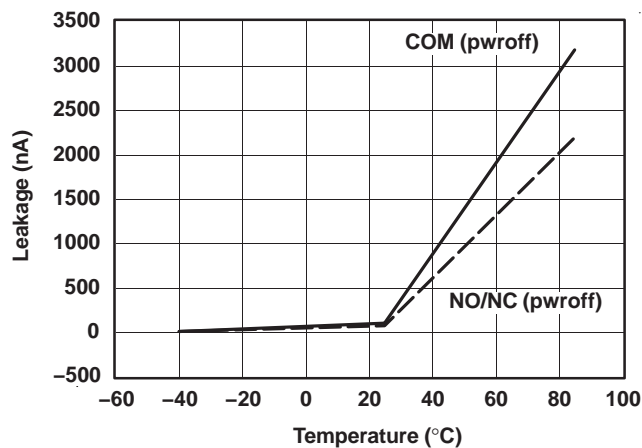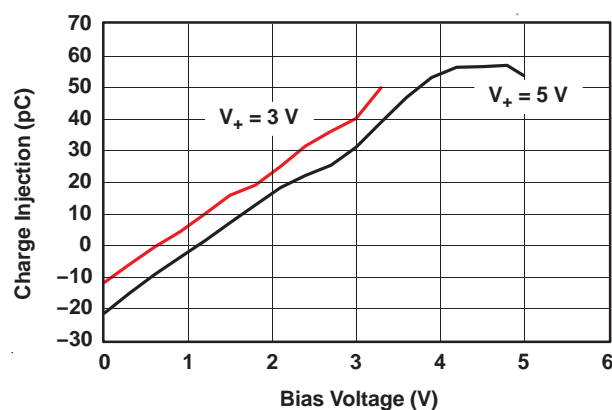(V$_+$ = 3.3 V)

Figure 6. Leakage Current vs Temperature
(V$_+$ = 5 V)
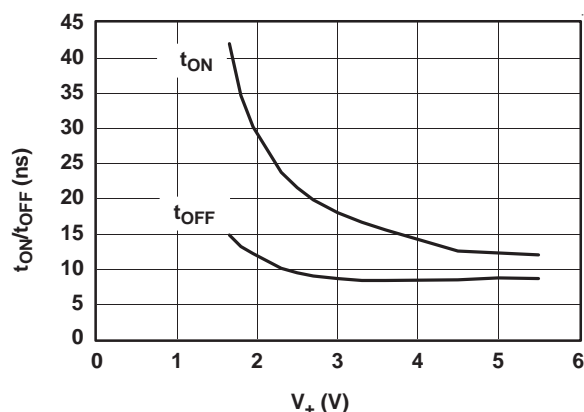

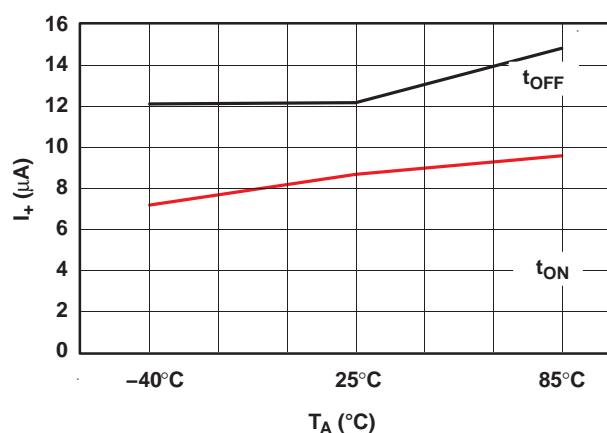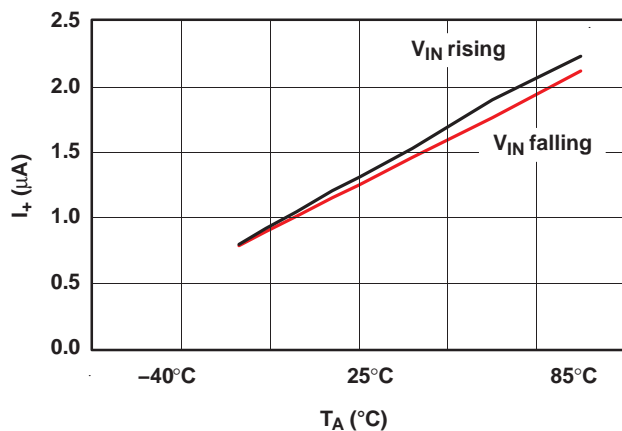Figure 7. Charge Injection vs Bias Voltage

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TYPICAL PERFORMANCE (continued)

Figure 8. t_{ON} and t_{OFF} vs Supply Voltage

Figure 9. I_+ vs Temperature

Figure 10. I_+ vs Temperature
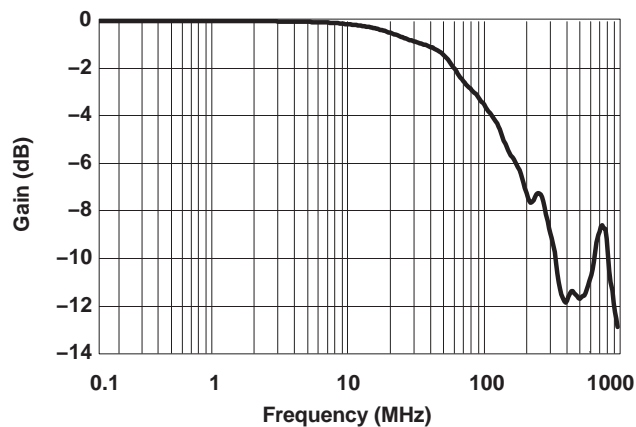
Figure 11. Bandwidth ($V_+ = 5$ V)
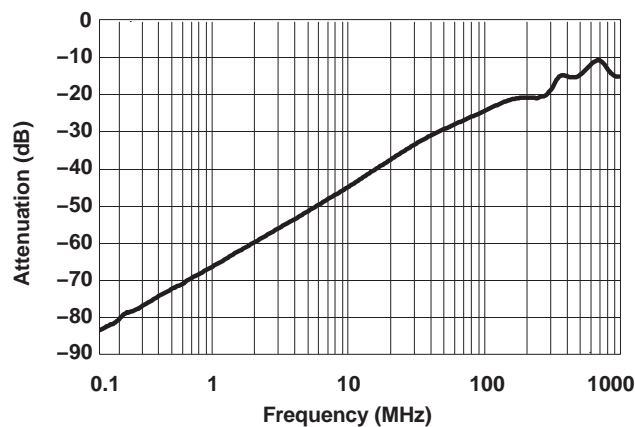
Figure 12. Attenuation vs Frequency
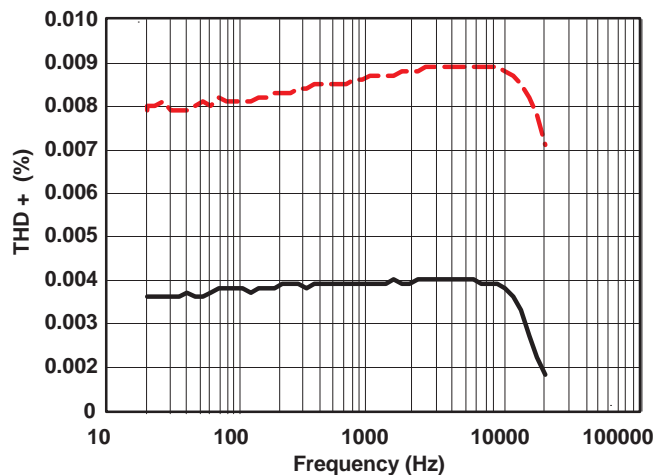
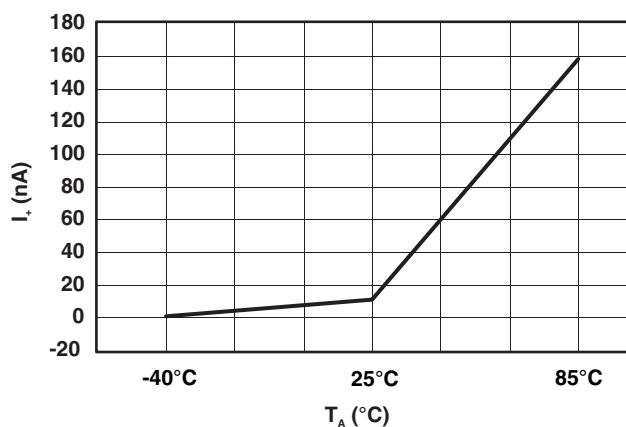Figure 13. Total Harmonic Distortion vs Frequency
($V_+ = 5$ V)

Product Folder Link(s): *TS5A3159A*

TYPICAL PERFORMANCE (continued)

Figure 14. Power-Supply Current vs Temperature
$(V_+ = 5\ V)$

PIN DESCRIPTION

NO.	NAME	DESCRIPTION
1	NO	Normally open
2	GND	Digital ground
3	NC	Normally closed
4	COM	Common
5	V_+	Power supply
6	IN	Digital control to connect COM to NO

Product Folder Link(s): TS5A3159A

PARAMETER DESCRIPTION

| SYMBOL	DESCRIPTION
V_{COM}	Voltage at COM
V_{NC}	Voltage at NC
V_{NO}	Voltage at NO
r_{on}	Resistance between COM and NC or COM and NO ports when the channel is on
r_{peak}	Peak on-state resistance over a specified voltage range
Δr_{on}	Difference of r_{on} between channels
$r_{on(flat)}$	Difference between the maximum and minimum value of r_{on} in a channel over the specified range of conditions
$I_{NC(OFF)}$	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the off state under worst-case input and output conditions
$I_{NC(PWROFF)}$	Leakage current measured at the NC port during the power-down condition, $V_+ = 0$
$I_{NO(OFF)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the off state under worst-case input and output conditions
$I_{NO(PWROFF)}$	Leakage current measured at the NO port during the power-down condition, $V_+ = 0$
$I_{NC(ON)}$	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the on state and the output (COM) being open
$I_{NO(ON)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the on state and the output (COM) being open
$I_{COM(ON)}$	Leakage current measured at the COM port, with the corresponding channel (COM to NO or COM to NC) in the on state and the output (NC or NO) being open
$I_{COM(PWROFF)}$	Leakage current measured at the COM port during the power-down condition, $V_+ = 0$
V_{IH}	Minimum input voltage for logic high for the control input (IN)
V_{IL}	Maximum input voltage for logic low for the control input (IN)
V_I	Voltage at (IN)
I_{IH}, I_{IL}	Leakage current measured at (IN)
t_{ON}	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog outputs (COM, NC, or NO) signal when the switch is turning on.
t_{OFF}	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog outputs (COM, NC, or NO) signal when the switch is turning off.
t_{BBM}	Break-before-make time. This parameter is measured under the specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO) when the control signal changes state.
Q_C	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NC, NO, or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_O$, C_L is the load capacitance and ΔV_O is the change in analog output voltage.
$C_{NC(OFF)}$	Capacitance at the NC port when the corresponding channel (NC to COM) is off
$C_{NO(OFF)}$	Capacitance at the NO port when the corresponding channel (NO to COM) is off
$C_{NC(ON)}$	Capacitance at the NC port when the corresponding channel (NC to COM) is on
$C_{NO(ON)}$	Capacitance at the NO port when the corresponding channel (NO to COM) is on
$C_{COM(ON)}$	Capacitance at the COM port when the corresponding channel (COM to NC or COM to NO) is on
C_{IN}	Capacitance of (IN)
OISO	OFF isolation of the switch is a measurement off-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM or NO to COM) in the off state.
X_{TALK}	Crosstalk is a measurement of unwanted signal coupling from an on channel to an off channel (NC to NO or NO to NC). This is measured in a specific frequency and in dB.
BW	Bandwidth of the switch. This is the frequency in which the gain of an on channel is –3 dB below the DC gain.
THD	Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio or root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic.
I_+	Static power supply current with the control (IN) pin at V_+ or GND

PARAMETER MEASUREMENT INFORMATION

$$r_{on} = \frac{V_{COM} - V_{NO} \text{ or } V_{NC}}{I_{COM}} \, \Omega$$

Channel On

$V_I = V_{IH}$ or V_{IL}
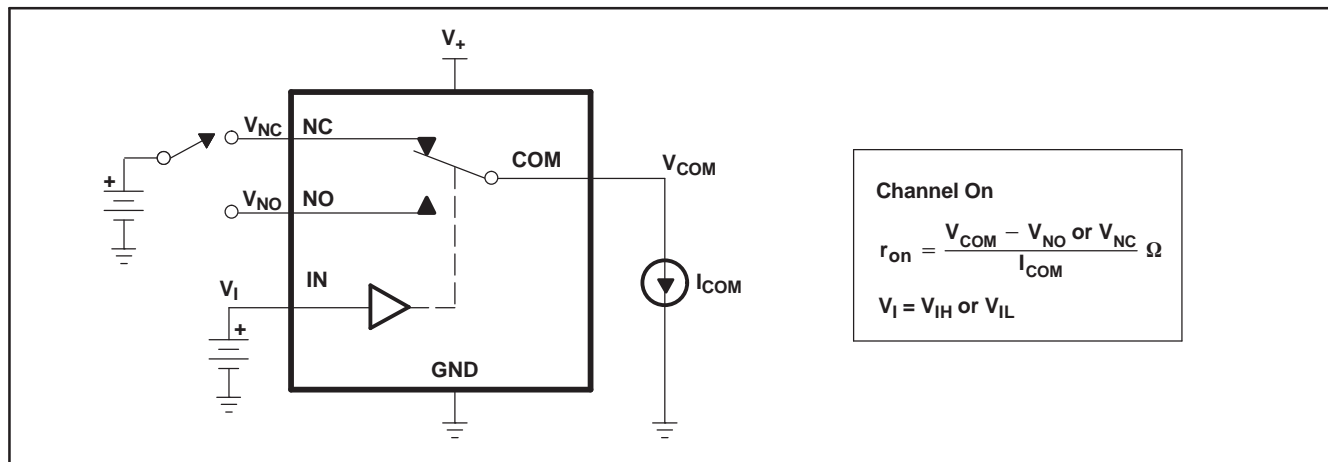
Figure 15. On-State Resistance (r_{on})
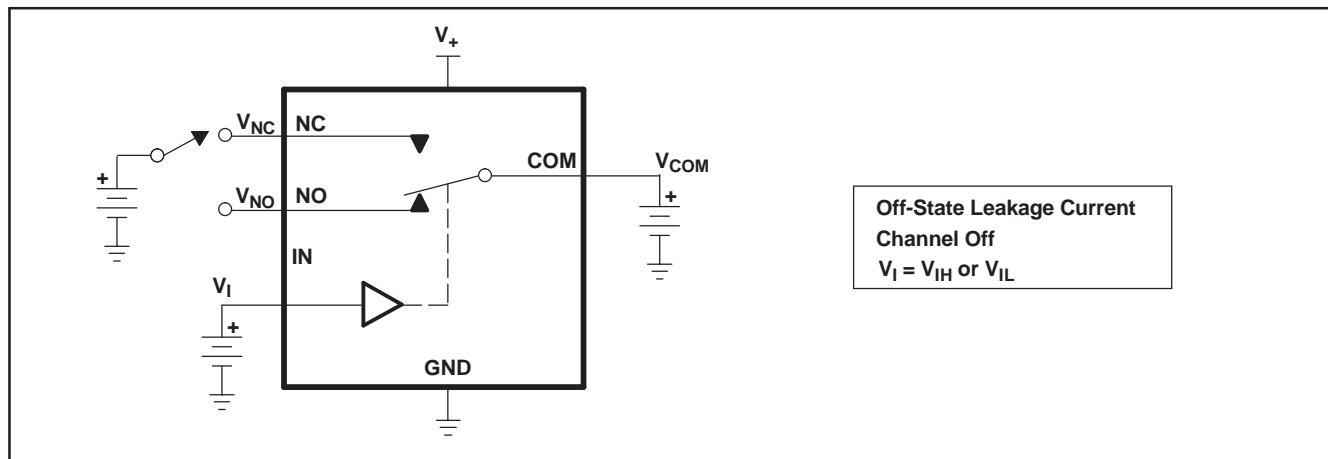

Off-State Leakage Current
Channel Off
$V_I = V_{IH}$ or V_{IL}

Figure 16. OFF-State Leakage Current ($I_{NC(OFF)}$, $I_{NC(PWROFF)}$, $I_{NO(OFF)}$, $I_{NO(PWROFF)}$, $I_{COM(OFF)}$, $I_{COM(PWROFF)}$)
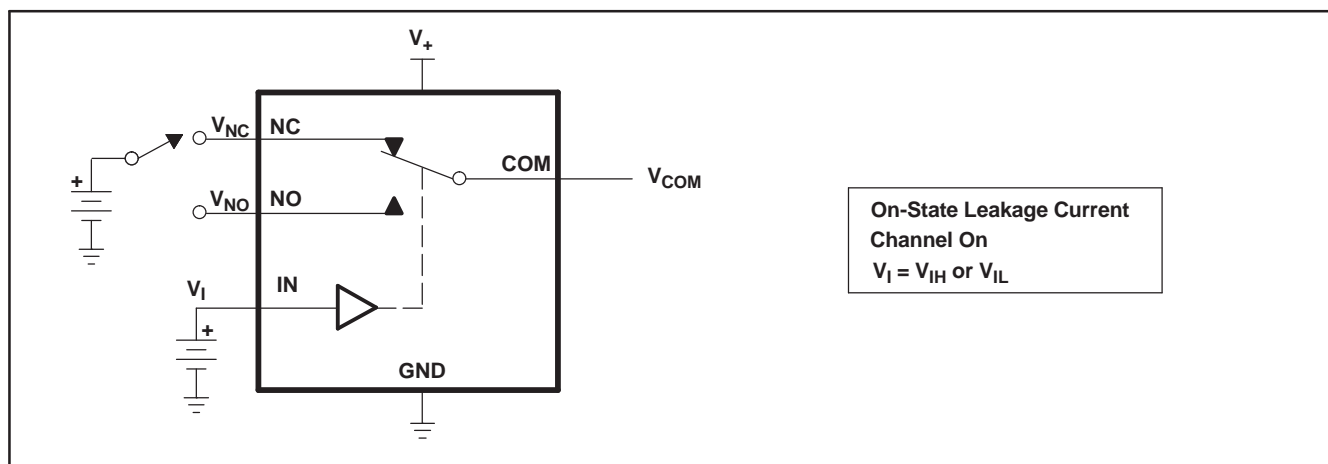

On-State Leakage Current
Channel On
$V_I = V_{IH}$ or V_{IL}

Figure 17. On-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$, $I_{NO(ON)}$)
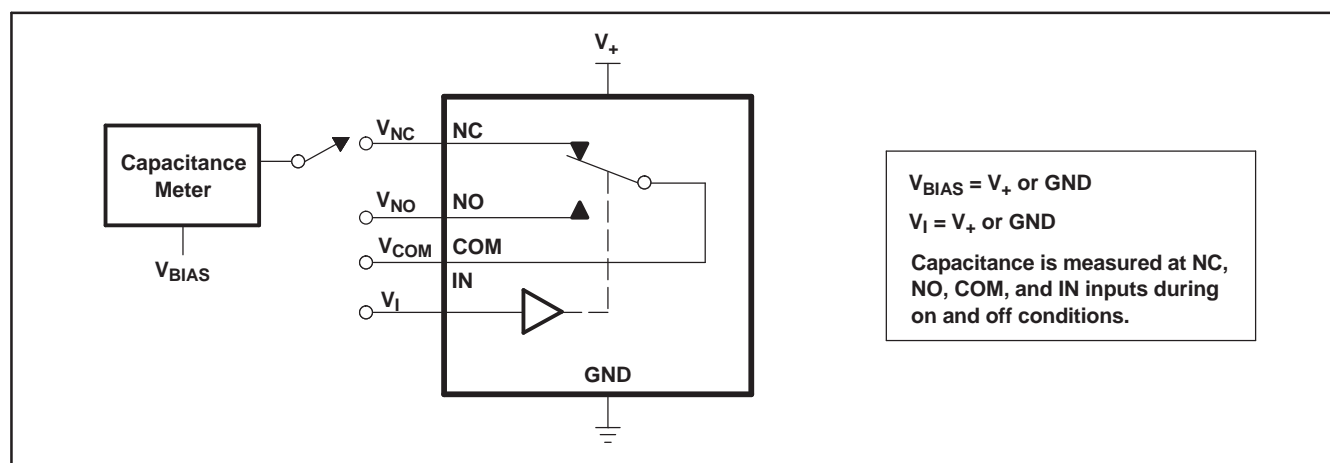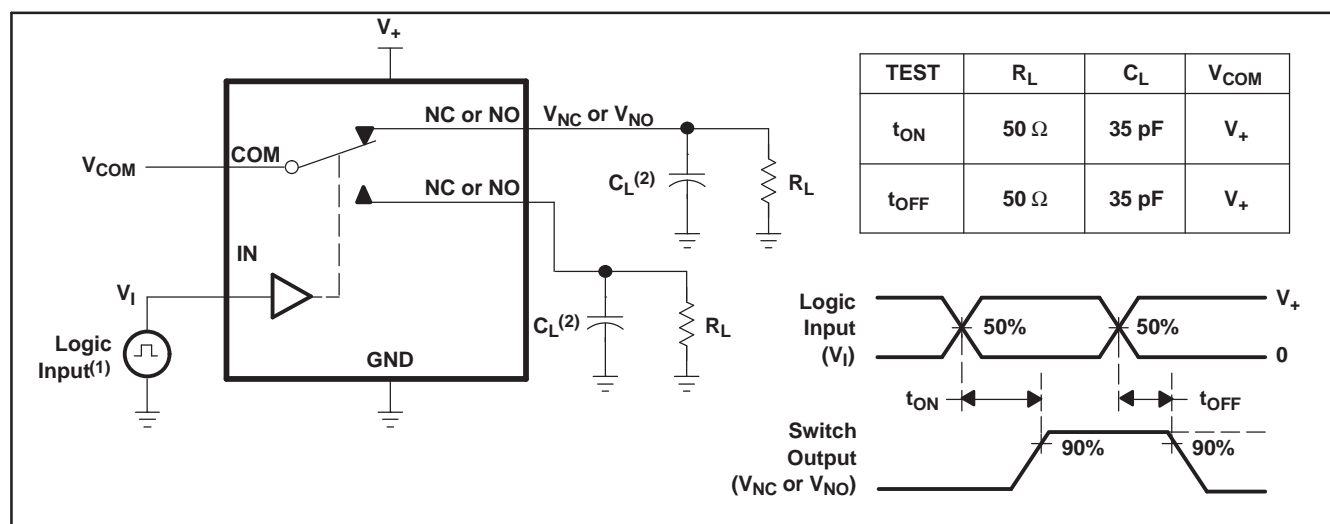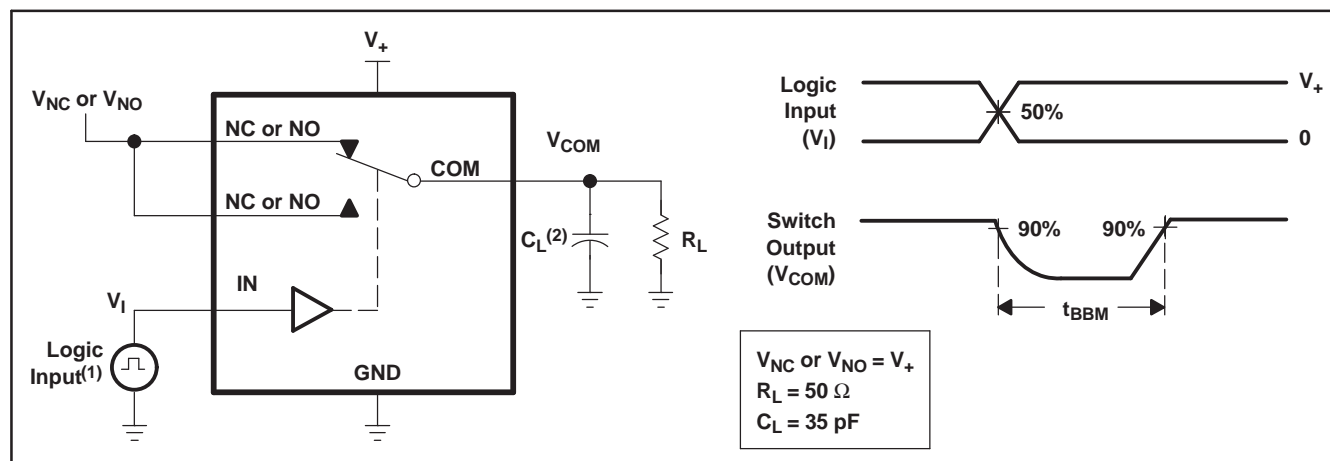
Figure 18. Capacitance (C_I, $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NO(OFF)}$, $C_{NC(ON)}$, $C_{NO(ON)}$)

A. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r < 5 ns, t_f < 5 ns.

B. C_L includes probe and jig capacitance.

Figure 19. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

Product Folder Link(s): *TS5A3159A*

A. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O = 50\ \Omega$, $t_r < 5$ ns, $t_f < 5$ ns.
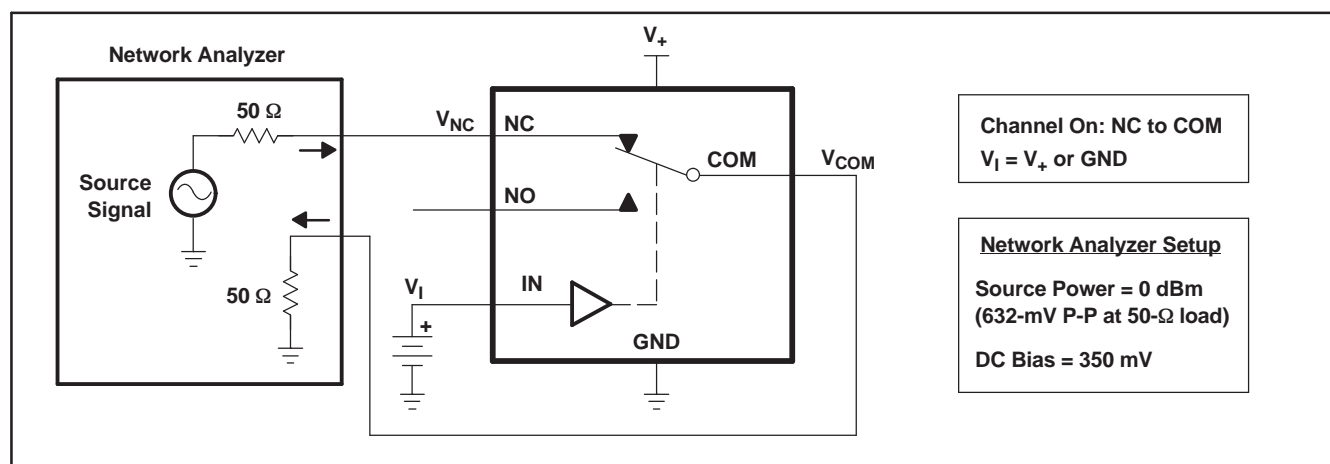
B. C_L includes probe and jig capacitance.

Figure 20. Break-Before-Make Time (t_{BBM})

Figure 21. Bandwidth (BW)

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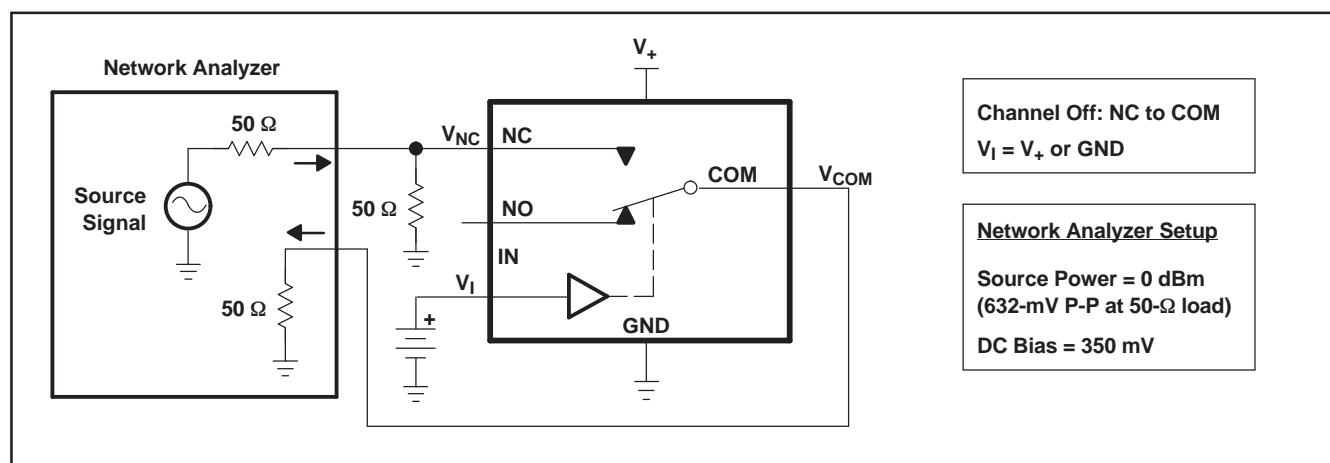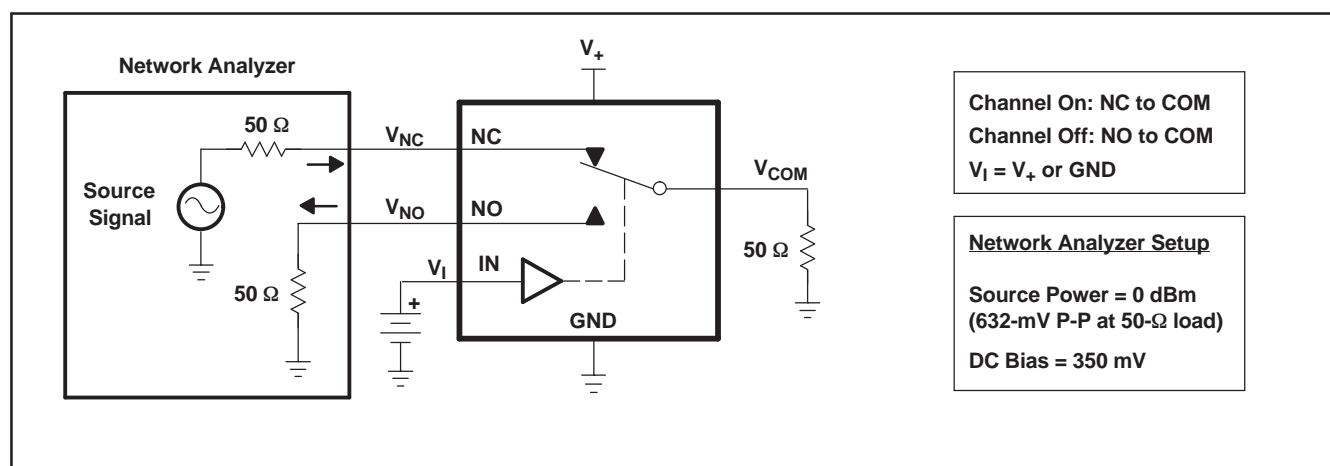www.ti.com

Figure 22. OFF Isolation (OISO)
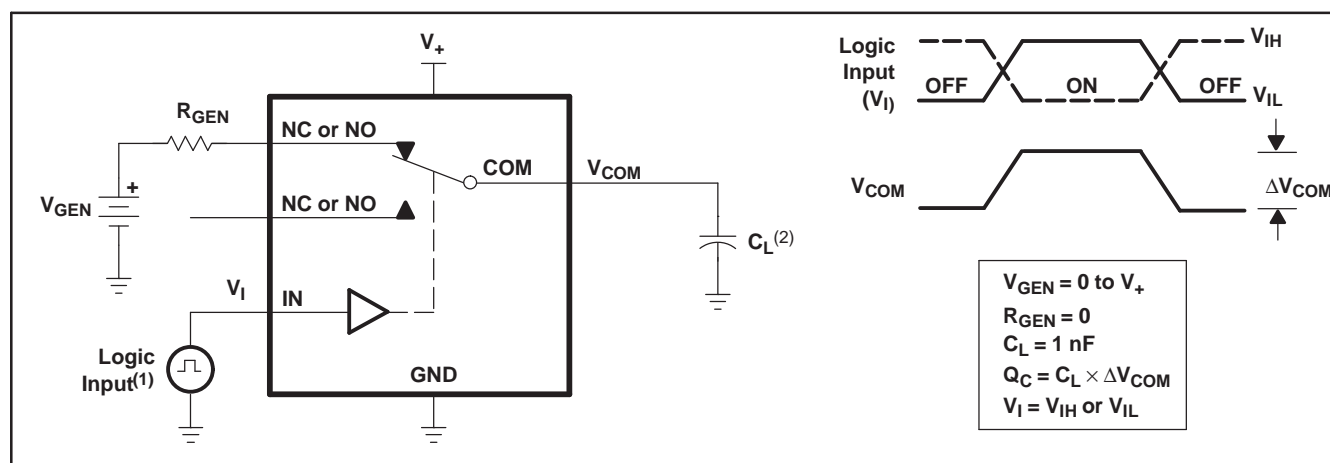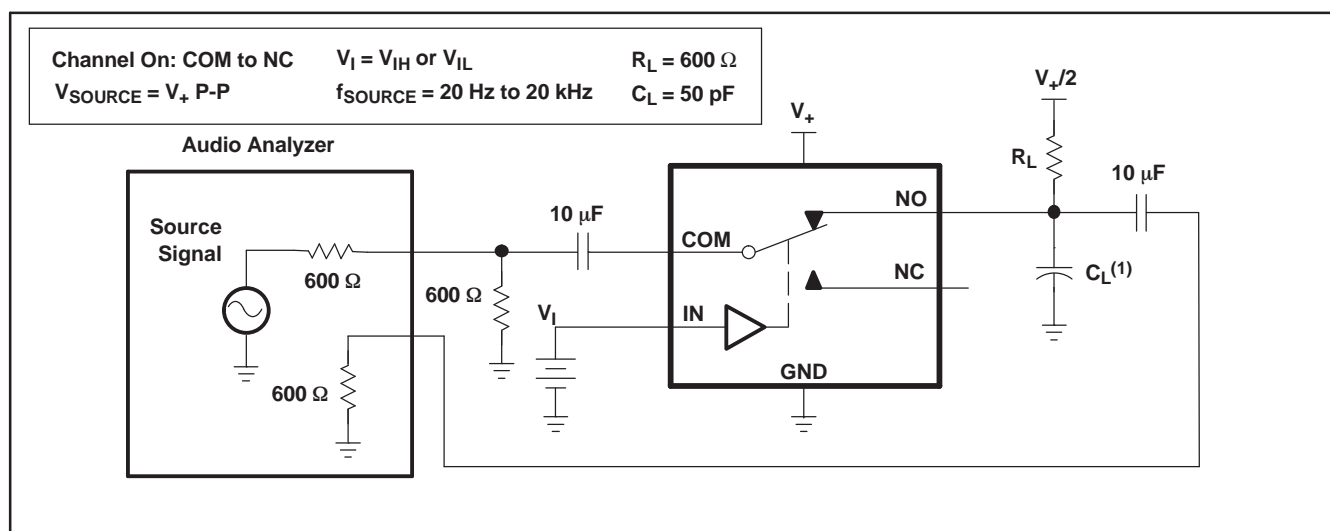

Figure 23. Crosstalk (X_{TALK})

A. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O = 50 \, \Omega$, $t_r < 5$ ns, $t_f < 5$ ns.

B. C_L includes probe and jig capacitance.

Figure 24. Charge Injection (Q_C)

A. C_L includes probe and jig capacitance.

Figure 25. Total Harmonic Distortion (THD)

PACKAGING INFORMATION

Orderable Device	Status [1]	Package Type	Package Drawing	Pins	Package Qty	Eco Plan [2]	Lead/Ball Finish	MSL Peak Temp [3]
TS5A3159ADBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159ADBVRE4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159ADBVRG4	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159ADBVT	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159ADBVTE4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159ADBVTG4	ACTIVE	SOT-23	DBV	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159ADCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159ADCKRE4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159ADCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159ADCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159ADCKTE4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159ADCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3159AYZPR	ACTIVE	DSBGA	YZP	6	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

[1] The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

[2] Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

[3] MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A3159ADBVR	SOT-23	DBV	6	3000	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
TS5A3159ADBVR	SOT-23	DBV	6	3000	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
TS5A3159ADBVT	SOT-23	DBV	6	250	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
TS5A3159ADBVT	SOT-23	DBV	6	250	180.0	9.2	3.23	3.17	1.37	4.0	8.0	Q3
TS5A3159ADCKR	SC70	DCK	6	3000	180.0	9.2	2.24	2.34	1.22	4.0	8.0	Q3
TS5A3159ADCKR	SC70	DCK	6	3000	180.0	8.4	2.24	2.34	1.22	4.0	8.0	Q3
TS5A3159ADCKT	SC70	DCK	6	250	180.0	8.4	2.24	2.34	1.22	4.0	8.0	Q3
TS5A3159AYZPR	DSBGA	YZP	6	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A3159ADBVR	SOT-23	DBV	6	3000	205.0	200.0	33.0
TS5A3159ADBVR	SOT-23	DBV	6	3000	202.0	201.0	28.0
TS5A3159ADBVT	SOT-23	DBV	6	250	205.0	200.0	33.0
TS5A3159ADBVT	SOT-23	DBV	6	250	202.0	201.0	28.0
TS5A3159ADCKR	SC70	DCK	6	3000	205.0	200.0	33.0
TS5A3159ADCKR	SC70	DCK	6	3000	202.0	201.0	28.0
TS5A3159ADCKT	SC70	DCK	6	250	202.0	201.0	28.0
TS5A3159AYZPR	DSBGA	YZP	6	3000	220.0	220.0	35.0

DBV (R−PDSO−G6)   PLASTIC SMALL−OUTLINE PACKAGE
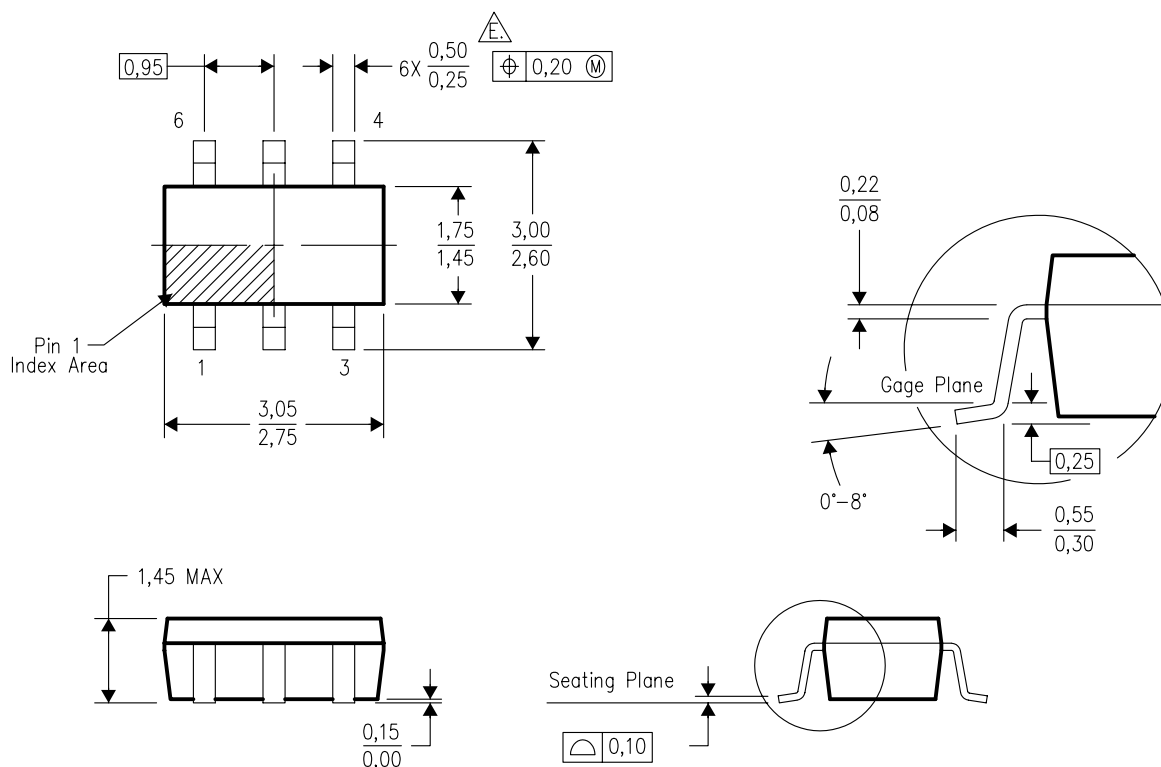
4073253−5/K 03/2006

NOTES: A. All linear dimensions are in millimeters.
        B. This drawing is subject to change without notice.
        C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
        D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
        E. Falls within JEDEC MO−178 Variation AB, except minimum lead width.

DCK (R–PDSO–G6)   PLASTIC SMALL–OUTLINE PACKAGE

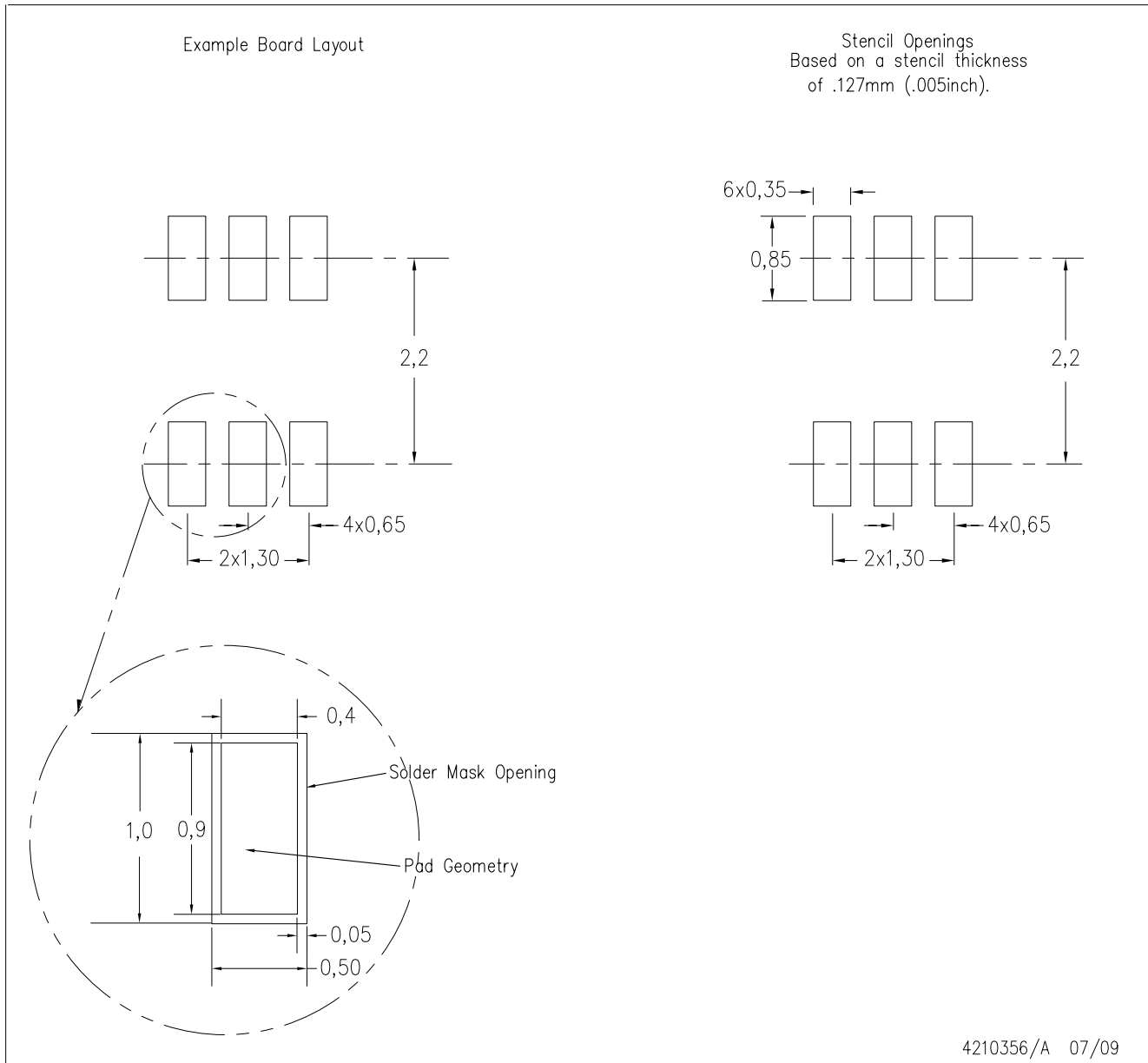4093553-4/G 01/2007

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
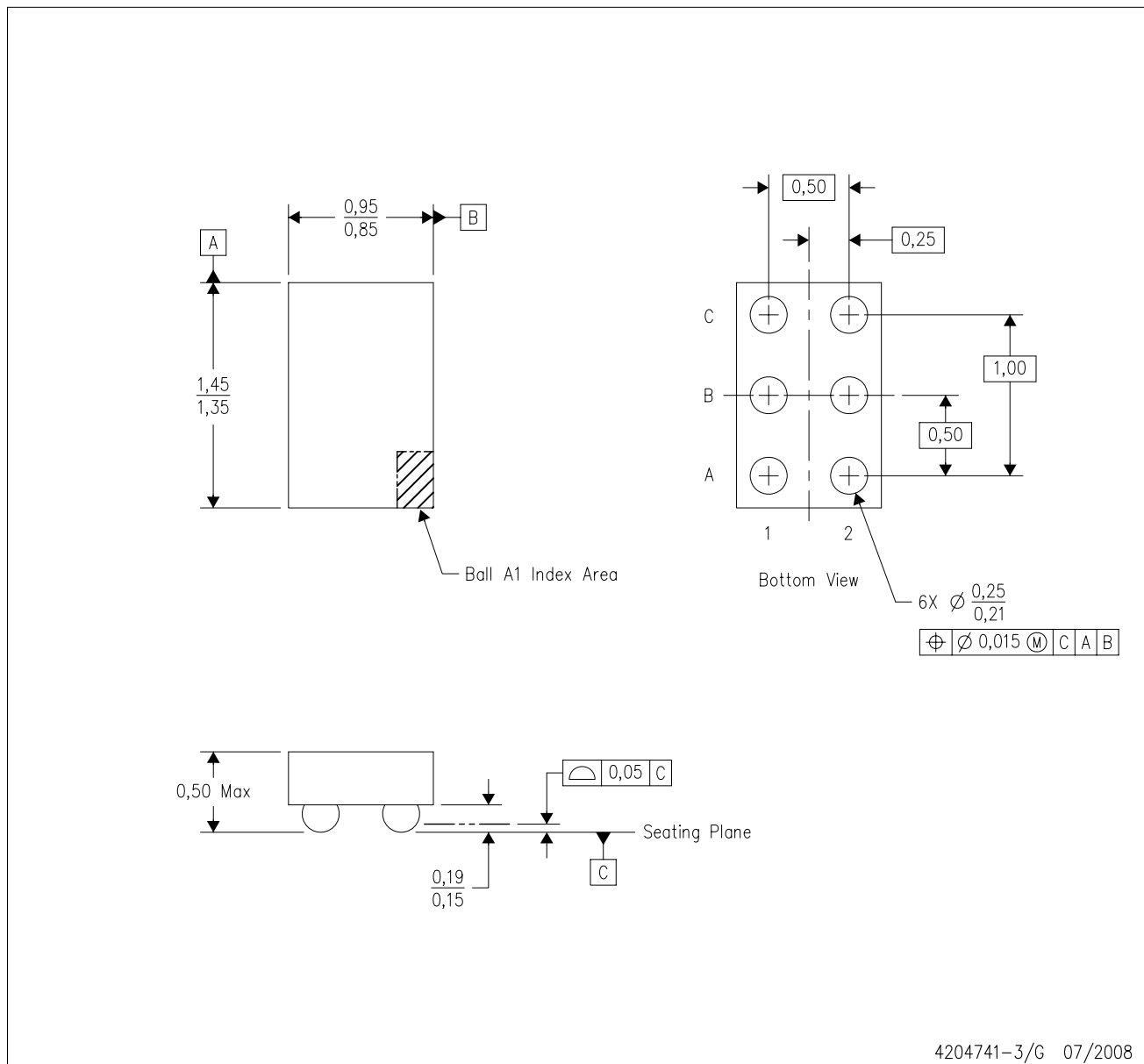D. Falls within JEDEC MO–203 variation AB.

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DCK (R-PDSO-G6)

Example Board Layout

2,2

6x0,35

0,85

2,2

4x0,65

2x1,30

4x0,65

2x1,30

0,4

Solder Mask Opening

1,0   0,9

Pad Geometry

0,05

0,50

4210356/A   07/09

NOTES: A.   All linear dimensions are in millimeters.
         B.   This drawing is subject to change without notice.
         C.   Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
         D.   Publication IPC−7351 is recommended for alternate designs.
         E.   Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
              contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric
              metal load solder paste. Refer to IPC−7525 for other stencil recommendations.

YZP (R−XBGA−N6)   DIE−SIZE BALL GRID ARRAY

$\frac{0,95}{0,85}$ [B]

[A]

$\frac{1,45}{1,35}$

Ball A1 Index Area

[0,50]

[0,25]

C

B

A

1   2

Bottom View

1,00

0,50

6X Ø $\frac{0,25}{0,21}$

[⊕ | Ø 0,015 Ⓜ | C | A | B]

0,50 Max

▢ 0,05 C

Seating Plane

$\frac{0,19}{0,15}$

C

4204741−3/G 07/2008

NOTES: A.   All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
         B.   This drawing is subject to change without notice.
         C.   NanoFree™ package configuration.
         D.   This package is lead−free. Refer to the 6 YEP package (drawing 4204725) for tin−lead (SnPb).

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